

- For the circuit shown in Fig. Derive an expression for the output impedance

$$R_{out} = R_1 \parallel r_{o2} \cdot [1 + (g_{m2} + g_{mb2})r_{o1}] \approx R_1 \parallel r_{o2} \cdot g_{m2}r_{o1}$$

- Design the circuit to get

Spec.		
DC Gain	≥ 23 dB	
BW	≥ 50 MHz	
Power Consumption	≤ 0.8 mW	
Cap Load	1.25 pF	

$$P_{cons} = V_{DD} I_D \leq 0.8 \text{ mW} \rightarrow \therefore I_{Dmax} \leq 666 \text{ uA}$$

$$GBW = A_V \cdot BW = \frac{g_{m1}}{2\pi C_L} \geq 710 \text{ MHz} \rightarrow g_{m1} \geq 5.576 \text{ mS} \rightarrow g_{m1} = 8 \text{ mS}$$

$$A_V = g_{m1}R_{out} \geq 14.2 \rightarrow R_{out} = 1775 \rightarrow \text{Choose } R_1 = 1800 \Omega$$

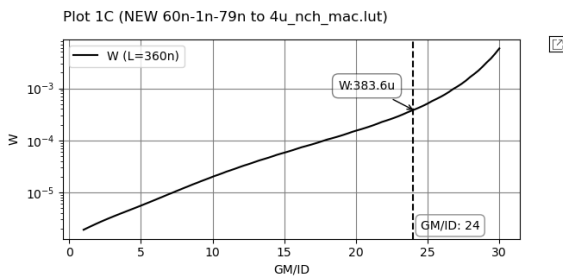
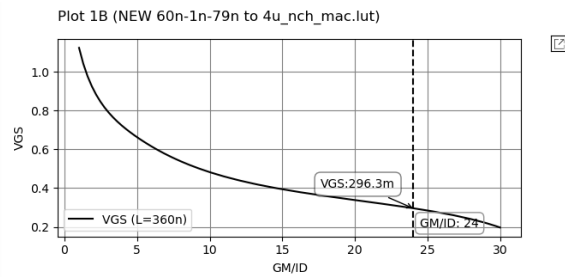
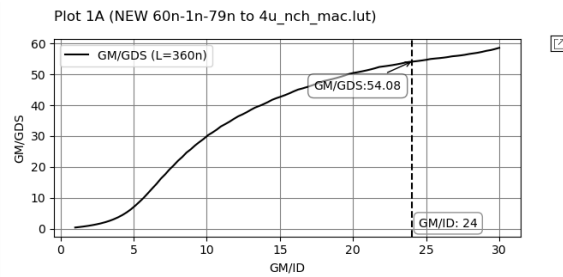
$$@ V_{OUT} = \frac{V_{DD}}{2} \text{ for maximum output swing} \rightarrow I_D = \frac{0.6}{1800} = 333.33 \text{ uA} \rightarrow \left(\frac{g_m}{I_D}\right)_1 = 24$$

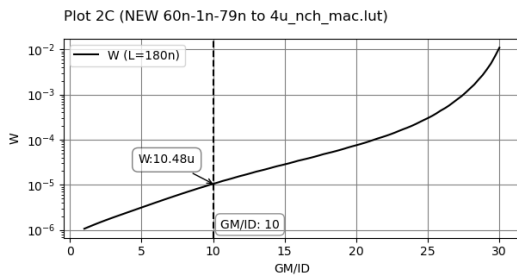
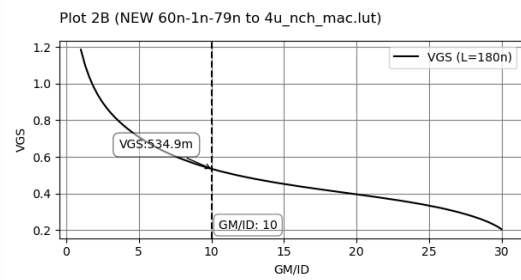
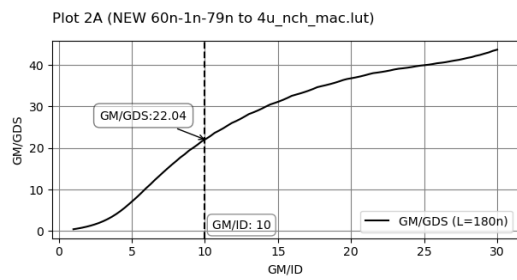
Assume M_2 operate in SI for large r_{o2} and Assume $r_{o1} = r_{o2} = r_o$

$$\therefore \text{set } \left(\frac{g_m}{I_D}\right)_2 = 10 \rightarrow g_{m2} = 3.33 \text{ mS} \rightarrow R_{out} = R_1 \parallel r_o^2 \cdot g_{m2} \rightarrow r_o = 6195 \Omega$$

$$\therefore \left(\frac{g_m}{g_{ds}}\right)_1 = 49.56 \rightarrow \left(\frac{g_m}{g_{ds}}\right)_2 = 20.63$$

For M1

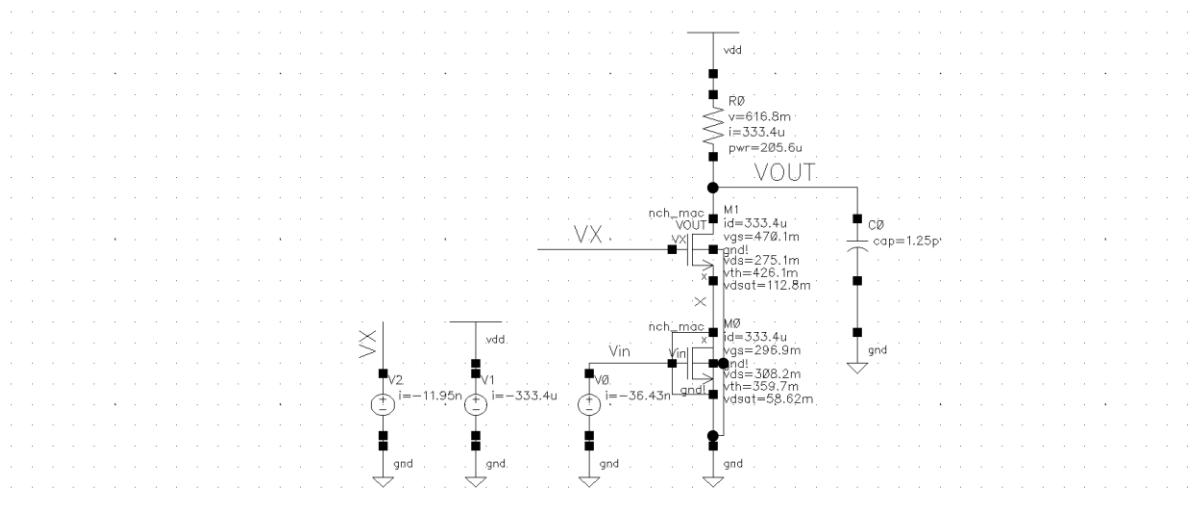




After Simulations, I need to increase the R1 to 1900

Simulations Results

- DC OP



- Vout AC Analysis

AC Analysis 'ac': freq = (1 Hz -> 100 GHz)

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